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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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April 2016

FDD8445_F085

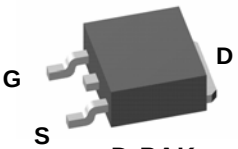
N-Channel PowerTrench® MOSFET
40V, 50A, 8.7mΩ

Features

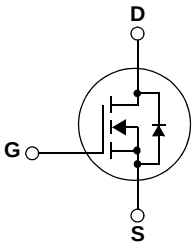
- Typ $R_{DS(on)}$ = 6.7mΩ at V_{GS} = 10V, I_D = 50A
- Typ $Q_{g(10)}$ = 45nC at V_{GS} = 10V, I_D = 50A
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems



D-PAK
(TO-252)



For current package drawing, please refer to the Fairchild web-site at http://www.fairchildsemi.com/package-drawings/TO/TO252A03.pdf.

MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	40	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current Continuous (V_{GS} = 10V)	50	A
	Pulsed	Figure 4	
E_{AS}	Single Pulse Avalanche Energy (Note 1)	144	mJ
P_D	Power Dissipation	79	W
	Derate above 25°C	0.53	W/°C
T_J, T_{STG}	Operating and Storage Temperature	-55 to +175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	1.9	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, 1in^2 copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8445	FDD8445_F085	TO-252AA	13”	12mm	2500 units

Notes:
1: Starting T_J = 25°C, L = 0.18mH, I_{AS} = 40A
2: A suffix as “…F085P” has been temporarily introduced in order to manage a double source strategy as Fairchild has officially announced in Aug 2014.

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Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
B_{VDSS}	Drain to Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V	40	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 32V, V_{GS} = 0V	-	-	1	μA
		V_{DS} = 32V, V_{GS} = 0V, T_A = 150°C	-	-	250	μA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V	-	-	±100	nA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA	2	2.8	4	V
$r_{DS(on)}$	Drain to Source On Resistance	I_D = 50A, V_{GS}= 10V	-	6.7	8.7	mΩ
		I_D = 50A, V_{GS}= 10V, T_J = 175°C	-	12.5	16.3	mΩ
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz	-	3040	4050	pF
C_{oss}	Output Capacitance		-	295	390	pF
C_{rss}	Reverse Transfer Capacitance		-	178	270	pF
R_G	Gate Resistance	f = 1MHz	-	1.7	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	V_{GS} = 0 to 10V, V_{DD} = 20V, I_D = 50A	-	45	59	nC
$Q_{g(TH)}$	Threshold Gate Charge	V_{GS} = 0 to 2V, V_{DD} = 20V, I_D = 50A		5.8	7.6	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = 20V, I_D = 50A	-	12.5	-	nC
Q_{gd}	Gate to Drain “Miller“ Charge	V_{DD} = 20V, I_D = 50A	-	10.5	-	nC

Switching Characteristics

t_{on}	Turn-On Time	V_{DD} = 20V, I_D = 50A, V_{GS} = 10V, R_{GS} = 2Ω	-	-	138	ns
$t_{d(on)}$	Turn-On Delay Time		-	10	-	ns
t_r	Rise Time		-	82	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	26	-	ns
t_f	Fall Time		-	9.6	-	ns
t_{off}	Turn-Off Time		-	-	53	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	I_{SD} = 50A	-	-	1.25	V
		I_{SD} = 25A	-	-	1.0	V
t_{rr}	Reverse Recovery Time	I_{SD} = 50A, dI_{SD}/dt = 100A/μs	-	-	39	ns
Q_{rr}	Reverse Recovery Charge		-	-	38	nC

Typical Characteristics

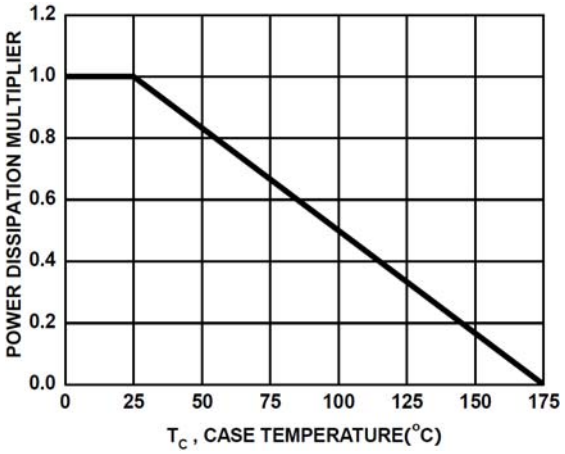


Figure 1. Normalized Power Dissipation vs Case Temperature

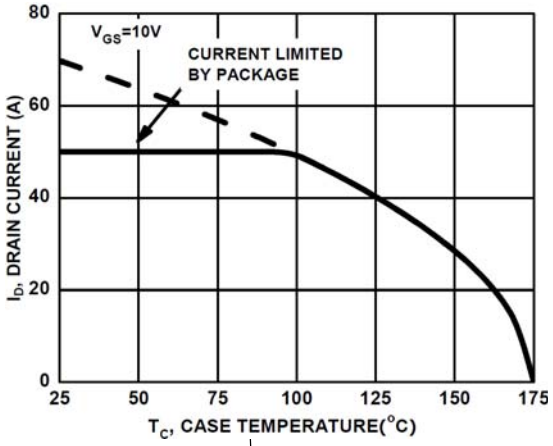


Figure 2. Maximum Continuous Drain Current vs Case Temperature

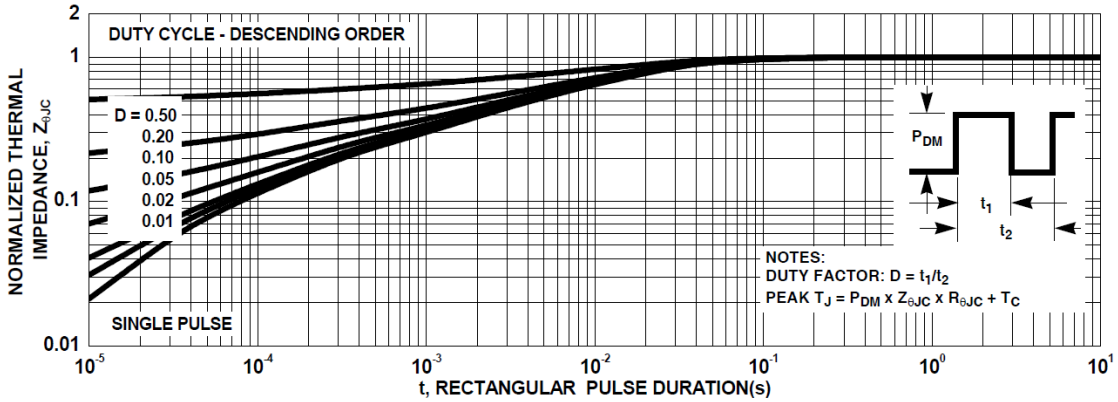


Figure 3. Normalized Maximum Transient Thermal Impedance

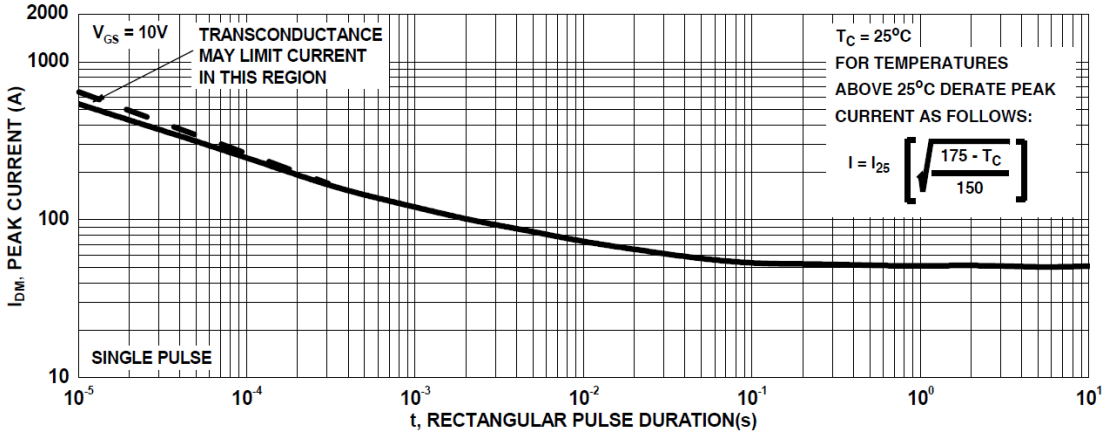


Figure 4. Peak Current Capability

Typical Characteristics

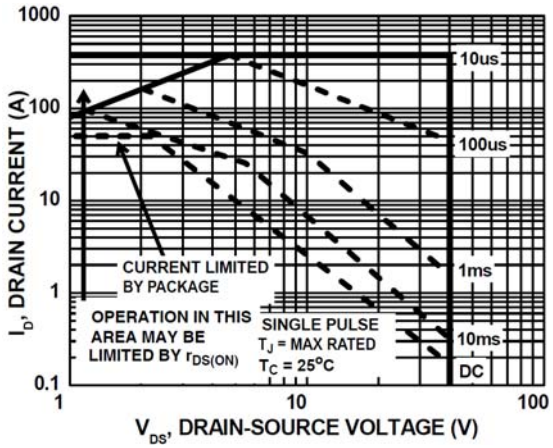
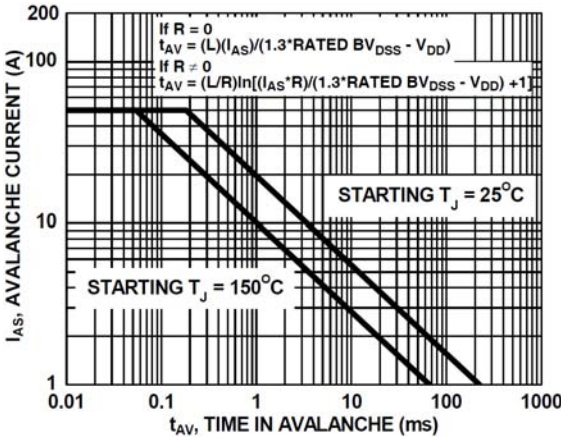


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

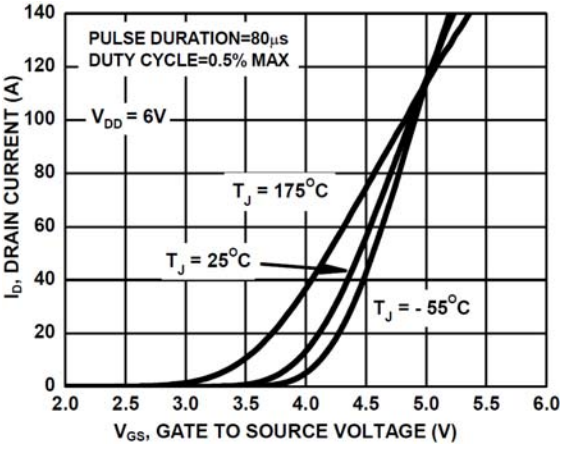


Figure 7. Transfer Characteristics

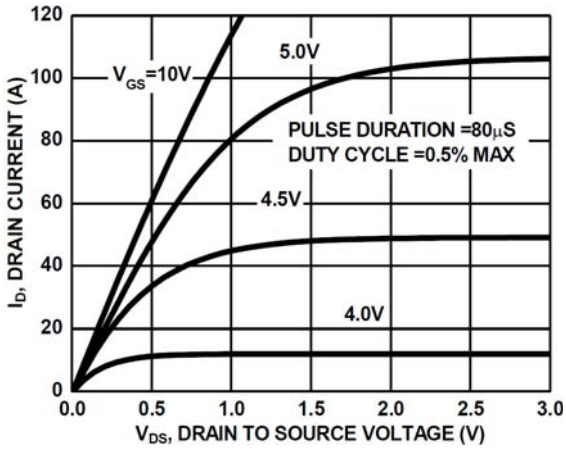


Figure 8. Saturation Characteristics

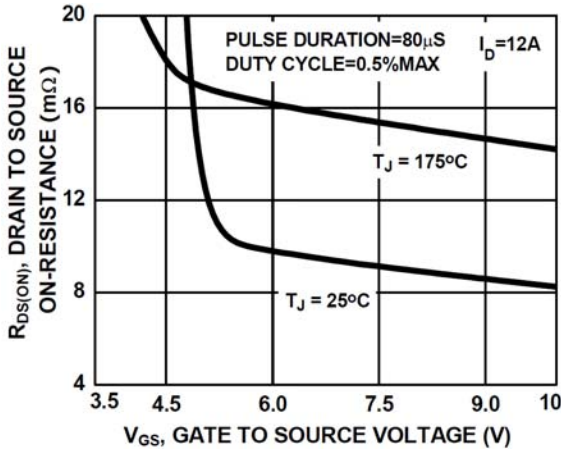


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

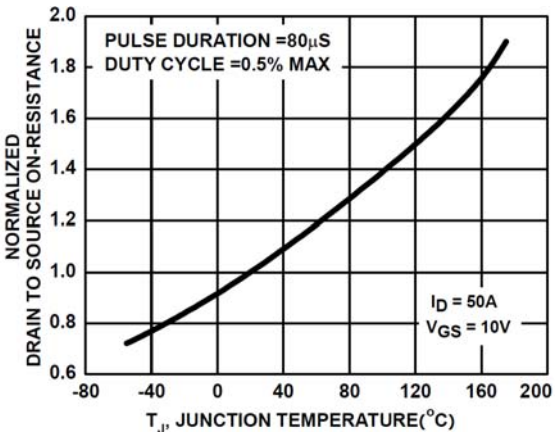


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

Typical Characteristics

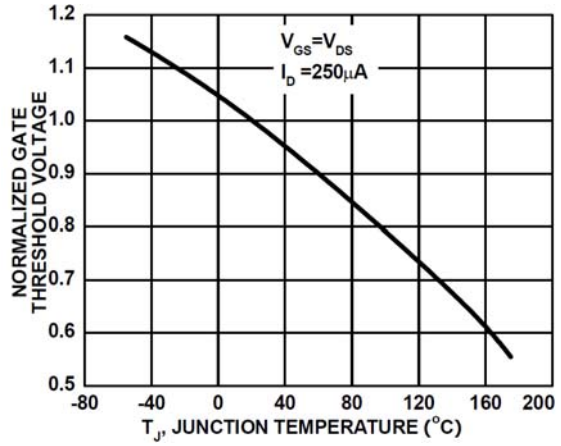


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

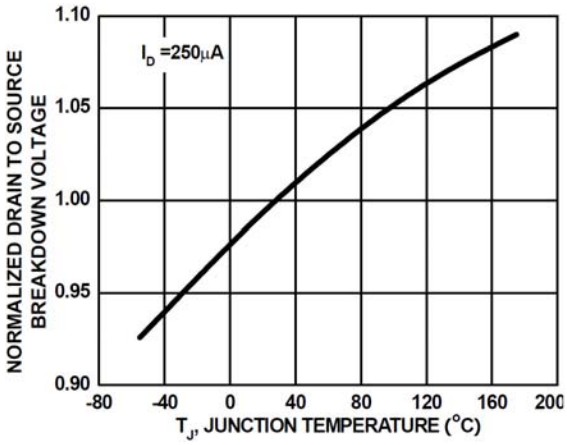


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

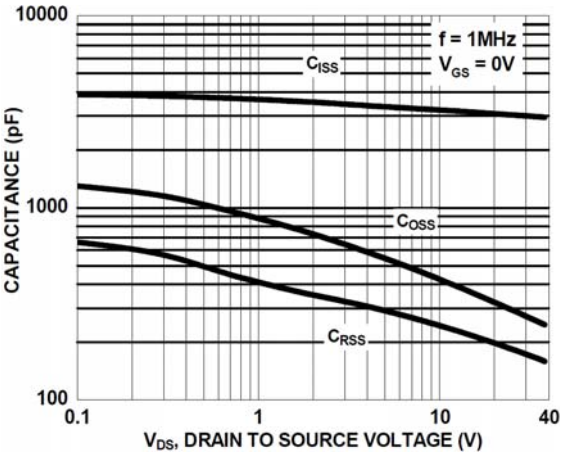


Figure 13. Capacitance vs Drain to Source Voltage

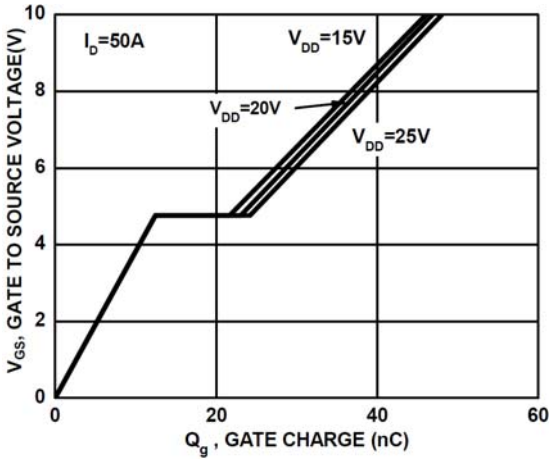
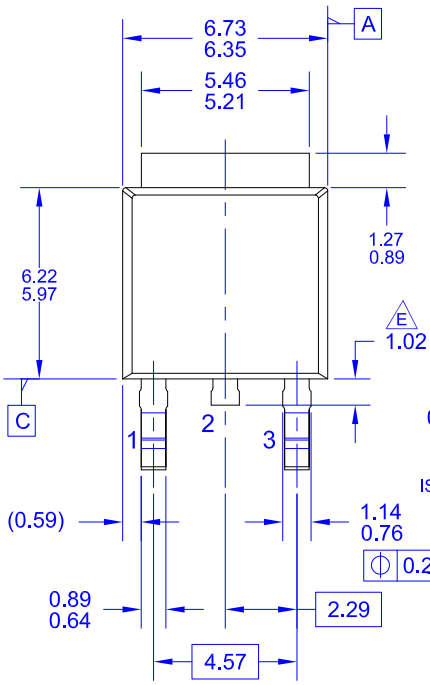
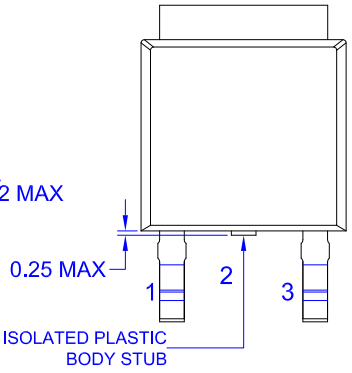


Figure 14. Gate Charge vs Gate to Source Voltage



NON-DIODE PRODUCTS VERSION



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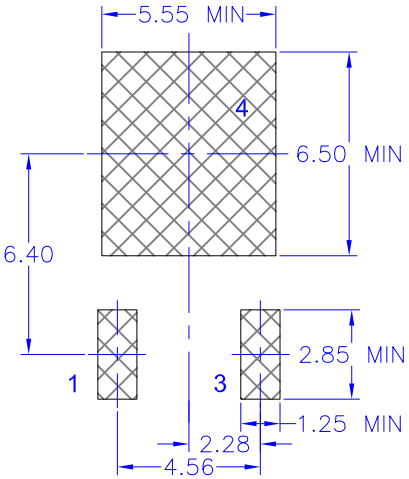
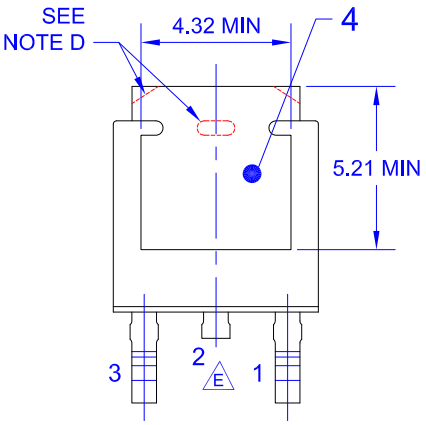


LAND PATTERN RECOMMENDATION



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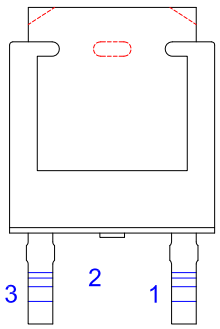

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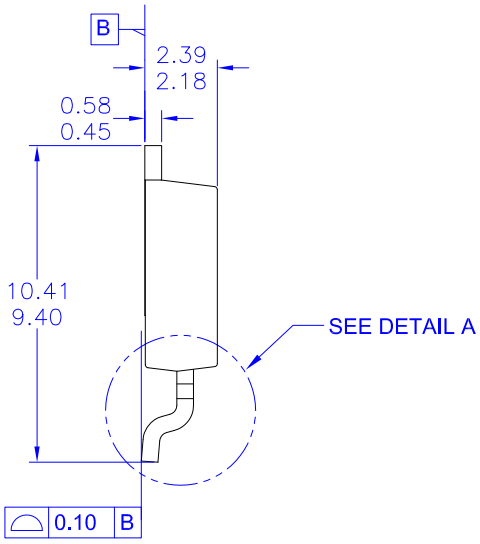

NOTES: UNLESS OTHERWISE SPECIFIED

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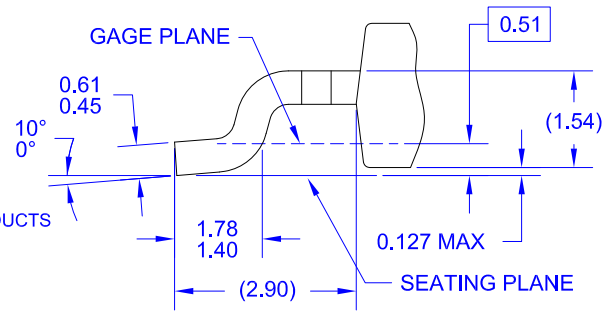
C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009.
D) SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED CORNERS OR EDGE PROTRUSION.
E) TRIMMED METAL CENTER LEAD IS PRESENT ON FOR NON-DIODE PRODUCTS
F) DIMENSIONS ARE EXCLUSIVE OF BURS, MOLD FLASH AND TIE BAR EXTRUSIONS.
G) LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD TO228P991X239-3N.
H) DRAWING NUMBER AND REVISION: MKT-TO252A03REV11



DETAIL A
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